VD55G1

804x704 advanced global shutter with 2.16 µm pixel, and small die size



life.augmented

Order code	Description
VD55G1CCB0/RW	Bare die

Application

Engineered for high performance computer vision applications, including AR/VR, personal and industrial robotics, drones, barcodes, biometrics and gestures, embedded vision, or scene recognition.

Typical use cases where high performance near-IR sensing is key. Also demanding computer vision on scene with movement requiring no shutter artifacts.

Features

- Compact global shutter technology (40 nm/65 nm)
 - High performance 2.16 μm x 2.16 μm BSI deep CDTI pixel
- Smallest global shutter 804x704 pixels with a 5.9 mm² footprint
 - Die size of only 2.7 mm x 2.2 mm; smaller than VGA equivalents
 - Small pixel array size of 1.73 mm x 1.73 mm
 - Optical format 1/10" with 600x600 crop
- Disruptive streaming modes, with ST in-pixel, enabling features with a single frame only for ultralow latency and power
 - Differential mode: ultrafast change tracking, event-like image
 - Background removal, without host processing
 - Spatial HDR, enabling 90dB+, without frame ghosting or latency
- Autonomous auto wake-up mode, with always-on scene change detection. Host can be fully off, with only VD55G1 consuming
 - 1.0 mW at 1 Hz
 - 1.5 mW at 5 Hz
 - 2.7 mW at 10 Hz
- Very low power consumption
 - 800x700 (full IQ, 5 msec exposure)
 - 7 mW at 10 fps
 - 35 mW at 48 fps
 - 640x480 (full IQ, 5 msec exposure)
 - 6 mW at 10 fps
 - 29 mW at 48 fps
 - Power consumption scaling with features/framerate and software standby
- High frame rate: 170 fps at 800x700, 260 fps at VGA and 460 fps at 320x240
- Disruptive I3C interface
 - 10x faster control interface, fully backward compatible with I²C
 - I3C image output in parallel of CSI-2 (10 fps at 320x240 or 5 fps at 400x400)
- Advanced raw ISP
 - Dynamic defective pixel correction
 - Smart noise pixel control (3 dB to 9 dB noise reduction)
 - Embedded multi auto exposure. Independent auto exposure per context
 - Different exposure for each pixel on the same frame (up to 3 exposures per frame)
 - Piece wise linear gamma (PWL), one setup per context, 4 points x/y per setup
 - Crop, analog, and digital binning (x2 and x4) and subsampling (x2 and x4)
 - Mirror/flip readout



- Flexible camera module system
 - Programmable sequences of 4-frame contexts, including illumination control
 - Up to 4-LED control outputs, synchronized on sensor integration periods with flexible timings and PWM (pulse-width modulation) control
 - Master/slave with external frame start
 - 1024 bits OTP available for the user/host
 - Integrated temperature sensor with ± 2°C accuracy [25°C; 85°C]
 - 1.2 Gb/s single lane transmitter MIPI CSI-2, with support down to 400 Mb/s
- Operating junction temperature: -30°C to 85°C
- High optical performance: QE peak >= 90% and MTF 940 nm at 55% Nyquist/2, dynamic range of 65 dB

Description

The VD55G1 is an advanced global shutter with 2.16 µm pixel. It has a small die size of 2.7 x 2.2 mm².

Revision history

Table 1. Document revision history

Date	Version	Changes
16-May-2023	1	Initial release

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